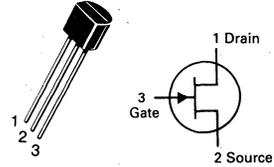


2N5638 thru 2N5640

CASE 29-04, STYLE 5
TO-92 (TO-226AA)



**JFETs
SWITCHING**

N-CHANNEL — DEPLETION

Refer to MPF4391 for graphs.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	Vdc
Drain-Gate Voltage	V_{DG}	30	Vdc
Reverse Gate-Source Voltage	V_{GSR}	30	Vdc
Forward Gate Current	I_{GF}	10	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	350 2.8	mW mW/°C
Junction Temperature Range	T_J	-65 to +150	°C
Storage Temperature Range	T_{stg}	-65 to +150	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Gate-Source Breakdown Voltage ($I_G = 10 \mu\text{Adc}$, $V_{DS} = 0$)	$V_{(BR)GSS}$	30	—	Vdc
Gate Reverse Current ($V_{GS} = -15 \text{ Vdc}$, $V_{DS} = 0$) ($V_{GS} = -15 \text{ Vdc}$, $V_{DS} = 0$, $T_A = 100^\circ\text{C}$)	I_{GSS}	— —	1.0 1.0	nAdc μAdc
Drain Cutoff Current ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = -12 \text{ Vdc}$) ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = -8.0 \text{ Vdc}$) ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = -6.0 \text{ Vdc}$) ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = -12 \text{ Vdc}$, $T_A = 100^\circ\text{C}$) ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = -8.0 \text{ Vdc}$, $T_A = 100^\circ\text{C}$) ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = -6.0 \text{ Vdc}$, $T_A = 100^\circ\text{C}$)	$I_{D(off)}$	— — — — — —	1.0 1.0 1.0 1.0 1.0 1.0	nAdc μAdc
ON CHARACTERISTICS				
Zero-Gate-Voltage Drain Current(1) ($V_{DS} = 20 \text{ Vdc}$, $V_{GS} = 0$)	I_{DSS}	50 25 5.0	— — —	mAdc
Drain-Source On-Voltage ($I_D = 12 \text{ mAdc}$, $V_{GS} = 0$) ($I_D = 6.0 \text{ mAdc}$, $V_{GS} = 0$) ($I_D = 3.0 \text{ mAdc}$, $V_{GS} = 0$)	$V_{DS(on)}$	— — —	0.5 0.5 0.5	Vdc
Static Drain-Source On Resistance ($I_D = 1.0 \text{ mAdc}$, $V_{GS} = 0$)	$r_{DS(on)}$	— — —	30 60 100	Ohms
SMALL-SIGNAL CHARACTERISTICS				
Static Drain-Source "ON" Resistance ($V_{GS} = 0$, $I_D = 0$, $f = 1.0 \text{ kHz}$)	$r_{ds(on)}$	— — —	30 60 100	Ohms
Input Capacitance ($V_{DS} = 0$, $V_{GS} = -12 \text{ Vdc}$, $f = 1.0 \text{ MHz}$)	C_{iss}	—	10	pF
Reverse Transfer Capacitance ($V_{DS} = 0$, $V_{GS} = -12 \text{ Vdc}$, $f = 1.0 \text{ MHz}$)	C_{rss}	—	4.0	pF

2N5638 thru 2N5640

ELECTRICAL CHARACTERISTICS (continued) ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic		Symbol	Min	Max	Unit	
SWITCHING CHARACTERISTICS						
Turn-On Delay Time		$I_{D(on)} = 12 \text{ mAdc}$ 2N5638	$t_{d(on)}$	—	4.0	ns
		6.0 mAdc 2N5639		—	6.0	
		3.0 mAdc 2N5640		—	8.0	
Rise Time	$V_{DD} = 10 \text{ Vdc}$, $V_{GS(on)} = 0$,	$I_{D(on)} = 12 \text{ mAdc}$ 2N5638	t_r	—	5.0	ns
		6.0 mAdc 2N5639		—	8.0	
		3.0 mAdc 2N5640		—	10	
Turn-Off Delay Time	$V_{GS(off)} = -10 \text{ Vdc}$, $R_{G'} = 50 \text{ ohms}$	$I_{D(on)} = 12 \text{ mAdc}$ 2N5638	$t_{d(off)}$	—	5.0	ns
		6.0 mAdc 2N5639		—	10	
		3.0 mAdc 2N5640		—	15	
Fall Time		$I_{D(on)} = 12 \text{ mAdc}$ 2N5638	t_f	—	10	ns
		6.0 mAdc 2N5639		—	20	
		3.0 mAdc 2N5640		—	30	

(1) Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 3.0\%$.